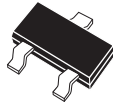


BCW31
SURFACE MOUNT
NPN GENERAL PURPOSE
SILICON TRANSISTOR



SOT-23 CASE

CentralTM

Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR BCW31, manufactured in the popular SOT-23 Surface Mount package, is an NPN General Purpose Switching and Amplification Transistor, suitable for applications requiring collector currents up to 100mA.

MARKING CODE: D1

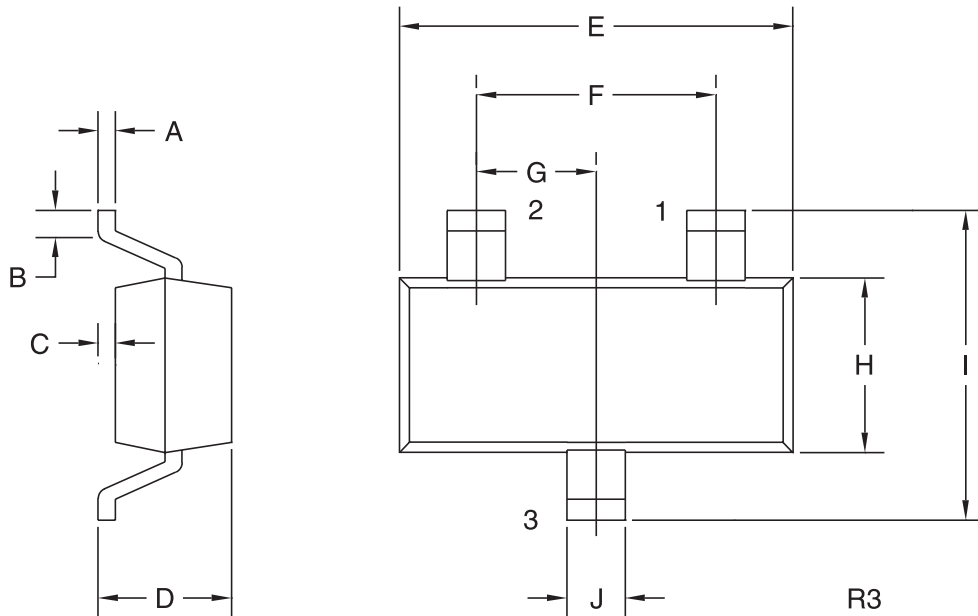
MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Collector Current	I_C	100	mA
Power Dissipation	P_D	350	mW
Operating and Storage			
Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	θ_{JA}	357	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
BV_{CBO}	$I_C=10\mu\text{A}$	30			V
BV_{CEO}	$I_C=2.0\text{mA}$	20			V
BV_{EBO}	$I_E=10\mu\text{A}$	5.0			V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.25	V
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$	0.55		0.70	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$	110		220	
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$			4.0	pF
NF	$I_C=0.2\text{mA}, V_{CE}=5.0\text{V}, R_S=2.0\text{k}\Omega,$ $f=1.0\text{MHz}, BW=200\text{Hz}$			10	dB

SOT-23 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) BASE
- 2) EMITTER
- 3) COLLECTOR

MARKING CODE: D1

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.003	0.007	0.08	0.18
B	0.006	-	0.15	-
C	-	0.005	-	0.13
D	0.035	0.043	0.89	1.09
E	0.110	0.120	2.80	3.05
F	0.075		1.90	
G	0.037		0.95	
H	0.047	0.055	1.19	1.40
I	0.083	0.098	2.10	2.49
J	0.014	0.020	0.35	0.50

SOT-23 (REV: R3)